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(54) Title: PHOTOVOLTAIC MODULE AND METHOD FOR MANUFACTURING THE SAME

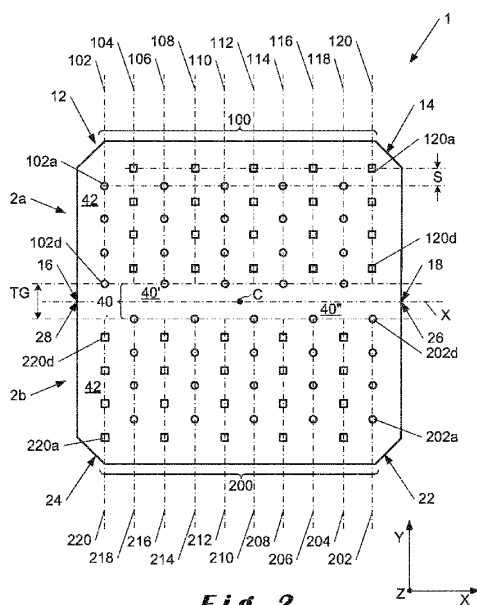


Fig. 2

(57) Abstract: The invention is achieved by an interdigitated back contact (IBC) photovoltaic device (1) comprising a substrate (2) having a structured layer (4) with first and second doped structures (4', 4''). The substrate (2) is divided, by a virtual axis (X) in a first portion (2a) and a second portion (2b). The first portion (2a) and second portion (2b) comprises, arranged on said first-type structures (4') and second type structures (4''), a plurality of electrical contacts (102a-d - 120a-d, 202a-d - 220a-d) that are aligned according to parallel first and second columns (100, 200) defining alternating negative and positive polarities. Each of the electrical contacts (102a-d - 120a-d) of the columns (100) of said first portion (2a) have a polarity opposite to the polarity of the electrical contacts (202a-d - 220a-d) of facing collinear columns (200) of said second portion (2b). Said first portion (2a) and second portion (2b) comprise at least one corner (12, 14) that is not a rectangular corner. The invention relates also to resized photovoltaic devices (10, 20) that are said photovoltaic devices (1) separated in two halves, and to modules (300) that comprise the resized photovoltaic devices (10, 20). The invention relates also to a method to realize the photovoltaic devices (1), the resized photovoltaic devices (10, 20) and the photovoltaic modules (300).